

# 74VHC4066AFT

## 1. Functional Description

- Quad Bilateral Switch

## 2. General

The 74VHC4066AFT is high-speed, low-voltage drive QUAD BILATERAL SWITCH fabricated with silicon gate C<sup>2</sup>MOS technology.

In 3 V and 5 V systems these can achieve high-speed operation with the low power dissipation that is a feature of CMOS.

It consists of four independent high speed switches capable of controlling either digital or analog signals while maintaining the CMOS low power dissipation.

The switches for each channel are turned ON by the control pin digital signals.

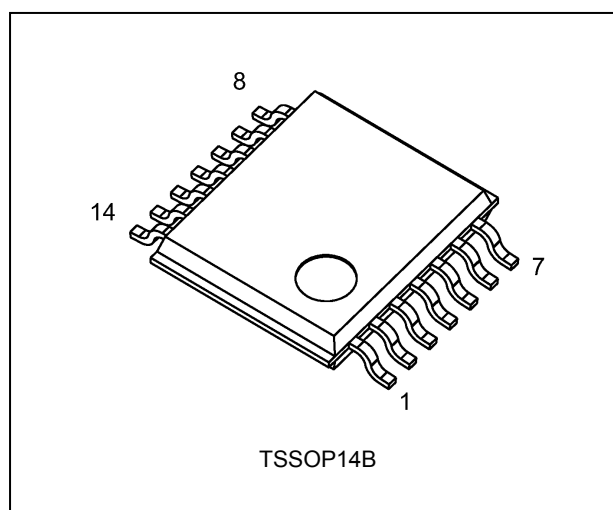
Control pin is equipped with a newly developed input protection circuit that avoids the need for a diode on the plus side (forward side from the input to the V<sub>CC</sub>). As a result, for example, 5.5 V signals can be permitted on the inputs even when the power supply voltage to the circuits is off. As a result of this input power protection, the 74VHC4066AFT can be used in a variety of applications, including in the system which has two power supplies, and in battery backup circuits.

## 3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: T<sub>opr</sub> = -40 to 125 °C
- (3) Low ON resistance: R<sub>ON</sub> = 45 Ω (typ.) at V<sub>CC</sub> = 3.0 V  
: R<sub>ON</sub> = 24 Ω (typ.) at V<sub>CC</sub> = 4.5 V
- (4) Low power dissipation: I<sub>CC</sub> = 2.0 μA (max) at T<sub>a</sub> = 25 °C
- (5) Input level: V<sub>IL</sub> = 0.8 V (max) at V<sub>CC</sub> = 3.0 V  
: V<sub>IH</sub> = 2.0 V (min) at V<sub>CC</sub> = 3.0 V
- (6) Power-down protection is provided on all control inputs.

Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

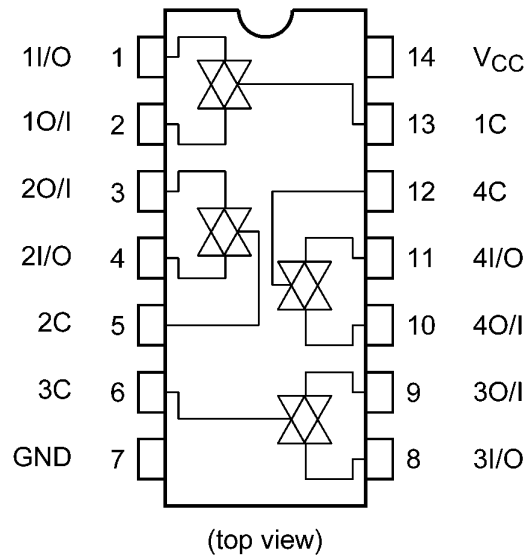
## 4. Packaging



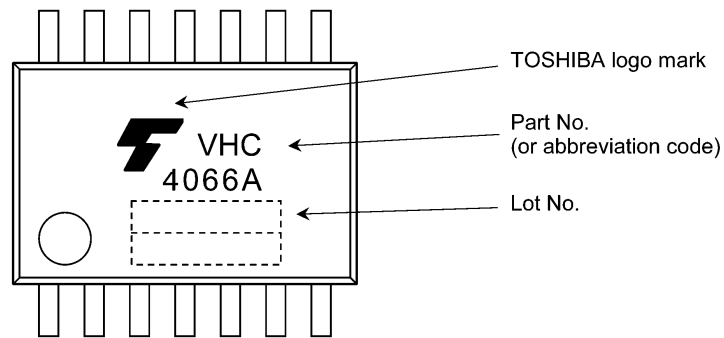
Start of commercial production

2014-10

**5. Pin Assignment**



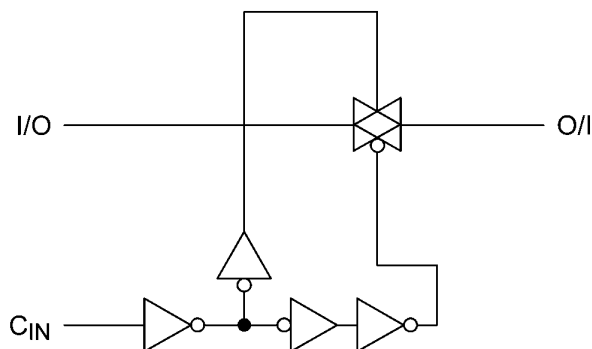
**6. Marking**



**7. Truth Table**

Control	Switch Function
H	On
L	Off

**8. System Diagram (per circuit)**



**9. Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	$V_{CC}$		-0.5 to 7.0	V
Input voltage	$V_{IN}$		-0.5 to 7.0	V
Switch I/O voltage	$V_{I/O}$		-0.5 to $V_{CC} + 0.5$	V
Input diode current	$I_{IK}$		-20	mA
I/O diode current	$I_{I/OK}$		$\pm 25$	mA
Switch through current	$I_T$		$\pm 25$	mA
$V_{CC}$ /ground current	$I_{CC}$		$\pm 50$	mA
Power dissipation	$P_D$	(Note 1)	180	mW
Storage temperature	$T_{stg}$		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of  $T_a = -40$  to  $85$  °C. From  $T_a = 85$  to  $125$  °C a derating factor of  $-3.25$  mW/°C shall be applied until 50 mW.

**10. Operating Ranges (Note)**

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	$V_{CC}$		2.0 to 5.5	V
Input voltage	$V_{IN}$		0 to 5.5	V
Switch I/O voltage	$V_{I/O}$		0 to $V_{CC}$	V
Operating temperature	$T_{opr}$		-40 to 125	°C
Input rise and fall times	$dt/dv$	$V_{CC} = 2.5 \pm 0.2$ V	0 to 200	ns/V
		$V_{CC} = 3.3 \pm 0.3$ V	0 to 100	
		$V_{CC} = 5.0 \pm 0.5$ V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device.  
Unused control inputs must be tied to either  $V_{CC}$  or GND.

**11. Electrical Characteristics**

**11.1. DC Characteristics (Unless otherwise specified,  $T_a = 25\text{ }^\circ\text{C}$ )**

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Min	Typ.	Max	Unit
High-level input voltage	$V_{IH}$	—	2.0	1.5	—	—	V
			3.0	2.0	—	—	
			4.5	3.15	—	—	
			5.5	3.85	—	—	
Low-level input voltage	$V_{IL}$	—	2.0	—	—	0.5	V
			3.0	—	—	0.8	
			4.5	—	—	1.35	
			5.5	—	—	1.65	
ON-resistance	$R_{ON}$	$V_{IN} = V_{IH}$ $V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2\text{ mA}$	2.3	—	200	—	$\Omega$
			3.0	—	45	86	
			4.5	—	24	37	
		$V_{IN} = V_{IH}$ $V_{I/O} = V_{CC}$ or GND $I_{I/O} = 2\text{ mA}$	2.3	—	28	73	
			3.0	—	22	38	
			4.5	—	17	27	
Difference of ON-resistance between switches	$\Delta R_{ON}$	$V_{IN} = V_{IH}$ $V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2\text{ mA}$	2.3	—	10	25	$\Omega$
			3.0	—	5	15	
			4.5	—	5	13	
Input/Output leakage current (Switch OFF)	$I_{OFF}$	$V_{OS} = V_{CC}$ or GND $V_{IS} = \text{GND}$ to $V_{CC}$ $V_{IN} = V_{IL}$	5.5	—	—	$\pm 0.1$	$\mu\text{A}$
Input/Output leakage current (Switch ON, output open)	$I_{I/O}$	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IH}$	5.5	—	—	$\pm 0.1$	$\mu\text{A}$
Control input leakage current	$I_{IN}$	$V_{IN} = V_{CC}$ or GND	5.5	—	—	$\pm 0.1$	$\mu\text{A}$
Quiescent supply current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	5.5	—	—	2.0	$\mu\text{A}$

**11.2. DC Characteristics (Unless otherwise specified,  $T_a = -40$  to  $85$  °C)**

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Min	Max	Unit
High-level input voltage	$V_{IH}$	—	2.0	1.5	—	V
			3.0	2.0	—	
			4.5	3.15	—	
			5.5	3.85	—	
Low-level input voltage	$V_{IL}$	—	2.0	—	0.5	V
			3.0	—	0.8	
			4.5	—	1.35	
			5.5	—	1.65	
ON-resistance	$R_{ON}$	$V_{IN} = V_{IH}$ $V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2$ mA	2.3	—	—	$\Omega$
			3.0	—	108	
			4.5	—	46	
		$V_{IN} = V_{IH}$ $V_{I/O} = V_{CC}$ or GND $I_{I/O} = 2$ mA	2.3	—	84	
			3.0	—	44	
			4.5	—	31	
Difference of ON-resistance between switches	$\Delta R_{ON}$	$V_{IN} = V_{IH}$ $V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2$ mA	2.3	—	35	$\Omega$
			3.0	—	20	
			4.5	—	18	
Input/Output leakage current (Switch OFF)	$I_{OFF}$	$V_{OS} = V_{CC}$ or GND $V_{IS} =$ GND to $V_{CC}$ $V_{IN} = V_{IL}$	5.5	—	$\pm 1.0$	$\mu A$
Input/Output leakage current (Switch ON, output open)	$I_{I/O}$	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IH}$	5.5	—	$\pm 1.0$	$\mu A$
Control input leakage current	$I_{IN}$	$V_{IN} = V_{CC}$ or GND	5.5	—	$\pm 1.0$	$\mu A$
Quiescent supply current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	5.5	—	20.0	$\mu A$

**11.3. DC Characteristics (Unless otherwise specified,  $T_a = -40$  to  $125$  °C)**

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Min	Max	Unit
High-level input voltage	$V_{IH}$	—	2.0	1.5	—	V
			3.0	2.0	—	
			4.5	3.15	—	
			5.5	3.85	—	
Low-level input voltage	$V_{IL}$	—	2.0	—	0.5	V
			3.0	—	0.8	
			4.5	—	1.35	
			5.5	—	1.65	
ON-resistance	$R_{ON}$	$V_{IN} = V_{IH}$ $V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2$ mA	2.3	—	—	$\Omega$
			3.0	—	125	
			4.5	—	54	
		$V_{IN} = V_{IH}$ $V_{I/O} = V_{CC}$ or GND $I_{I/O} = 2$ mA	2.3	—	105	$\Omega$
			3.0	—	55	
			4.5	—	39	
Difference of ON-resistance between switches	$\Delta R_{ON}$	$V_{IN} = V_{IH}$ $V_{I/O} = V_{CC}$ to GND $I_{I/O} = 2$ mA	2.3	—	45	$\Omega$
			3.0	—	25	
			4.5	—	23	
Input/Output leakage current (Switch OFF)	$I_{OFF}$	$V_{OS} = V_{CC}$ or GND $V_{IS} =$ GND to $V_{CC}$ $V_{IN} = V_{IL}$	5.5	—	$\pm 4.0$	$\mu A$
Input/Output leakage current (Switch ON, output open)	$I_{I/O}$	$V_{OS} = V_{CC}$ or GND $V_{IN} = V_{IH}$	5.5	—	$\pm 4.0$	$\mu A$
Control input leakage current	$I_{IN}$	$V_{IN} = V_{CC}$ or GND	5.5	—	$\pm 2.0$	$\mu A$
Quiescent supply current	$I_{CC}$	$V_{IN} = V_{CC}$ or GND	5.5	—	40.0	$\mu A$

**11.4. AC Characteristics (Unless otherwise specified,  $T_a = 25\text{ }^\circ\text{C}$ , Input:  $t_r = t_f = 3\text{ ns}$ )**

Characteristics	Symbol	Note	Test Condition	$V_{CC}$ (V)	Min	Typ.	Max	Unit
Phase difference between input to output	$\phi_{I/O}$		$C_L = 15\text{ pF}$ $R_L = 1\text{ k}\Omega$	2.5 ± 0.2	—	1.2	10	ns
				3.3 ± 0.3	—	0.8	6	
				5.0 ± 0.5	—	0.3	4	
			$C_L = 50\text{ pF}$ $R_L = 1\text{ k}\Omega$	2.5 ± 0.2	—	2.6	12	
				3.3 ± 0.3	—	1.5	9	
				5.0 ± 0.5	—	0.6	6	
Output enable time	$t_{PZL}$ , $t_{PZH}$		$C_L = 15\text{ pF}$ $R_L = 1\text{ k}\Omega$ See 12. AC Test Circuit, Figure 1	2.5 ± 0.2	—	3.3	15	ns
				3.3 ± 0.3	—	2.3	11	
				5.0 ± 0.5	—	1.6	7	
			$C_L = 50\text{ pF}$ $R_L = 1\text{ k}\Omega$ See 12. AC Test Circuit, Figure 1	2.5 ± 0.2	—	4.2	25	
				3.3 ± 0.3	—	3.0	18	
				5.0 ± 0.5	—	2.1	12	
Output disable time	$t_{PLZ}$ , $t_{PHZ}$		$C_L = 15\text{ pF}$ $R_L = 1\text{ k}\Omega$ See 12. AC Test Circuit, Figure 1	2.5 ± 0.2	—	6	15	ns
				3.3 ± 0.3	—	4.5	11	
				5.0 ± 0.5	—	3.2	7	
			$C_L = 50\text{ pF}$ $R_L = 1\text{ k}\Omega$ See 12. AC Test Circuit, Figure 1	2.5 ± 0.2	—	9.6	25	
				3.3 ± 0.3	—	7.2	18	
				5.0 ± 0.5	—	5.1	12	
Control input capacitance	$C_{IN}$		All types	—	3	—	pF	
Switch terminal capacitance	$C_{OS}$		See 12. AC Test Circuit, Figure 2	—	5.5	—	pF	
Feedthrough capacitance	$C_{IOS}$		See 12. AC Test Circuit, Figure 2	—	0.5	—	pF	
Power dissipation capacitance	$C_{PD}$	(Note 1)	See 12. AC Test Circuit, Figure 2	—	4.5	—	pF	

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$$

**11.5. AC Characteristics**  
 (Unless otherwise specified,  $T_a = -40$  to  $85$  °C, Input:  $t_r = t_f = 3$  ns)

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Min	Max	Unit
Phase difference between input to output	$\phi_{I/O}$	$C_L = 15$ pF $R_L = 1$ k $\Omega$	2.5 $\pm$ 0.2	—	16	ns
			3.3 $\pm$ 0.3	—	10	
			5.0 $\pm$ 0.5	—	7	
		$C_L = 50$ pF $R_L = 1$ k $\Omega$	2.5 $\pm$ 0.2	—	18	
			3.3 $\pm$ 0.3	—	12	
			5.0 $\pm$ 0.5	—	8	
Output enable time	$t_{PZL}, t_{PZH}$	$C_L = 15$ pF $R_L = 1$ k $\Omega$ See 12. AC Test Circuit, Figure 1	2.5 $\pm$ 0.2	—	20	ns
			3.3 $\pm$ 0.3	—	15	
			5.0 $\pm$ 0.5	—	10	
		$C_L = 50$ pF $R_L = 1$ k $\Omega$ See 12. AC Test Circuit, Figure 1	2.5 $\pm$ 0.2	—	32	
			3.3 $\pm$ 0.3	—	22	
			5.0 $\pm$ 0.5	—	16	
Output disable time	$t_{PLZ}, t_{PHZ}$	$C_L = 15$ pF $R_L = 1$ k $\Omega$ See 12. AC Test Circuit, Figure 1	2.5 $\pm$ 0.2	—	23	ns
			3.3 $\pm$ 0.3	—	15	
			5.0 $\pm$ 0.5	—	10	
		$C_L = 50$ pF $R_L = 1$ k $\Omega$ See 12. AC Test Circuit, Figure 1	2.5 $\pm$ 0.2	—	32	
			3.3 $\pm$ 0.3	—	22	
			5.0 $\pm$ 0.5	—	16	

**11.6. AC Characteristics**  
 (Unless otherwise specified,  $T_a = -40$  to  $125$  °C, Input:  $t_r = t_f = 3$  ns)

Characteristics	Symbol	Test Condition	$V_{CC}$ (V)	Min	Max	Unit
Phase difference between input to output	$\phi_{I/O}$	$C_L = 15$ pF $R_L = 1$ k $\Omega$	2.5 $\pm$ 0.2	—	20	ns
			3.3 $\pm$ 0.3	—	13	
			5.0 $\pm$ 0.5	—	9	
		$C_L = 50$ pF $R_L = 1$ k $\Omega$	2.5 $\pm$ 0.2	—	22	
			3.3 $\pm$ 0.3	—	14	
			5.0 $\pm$ 0.5	—	9.5	
Output enable time	$t_{PZL}, t_{PZH}$	$C_L = 15$ pF $R_L = 1$ k $\Omega$ See 12. AC Test Circuit, Figure 1	2.5 $\pm$ 0.2	—	23.5	ns
			3.3 $\pm$ 0.3	—	18	
			5.0 $\pm$ 0.5	—	12	
		$C_L = 50$ pF $R_L = 1$ k $\Omega$ See 12. AC Test Circuit, Figure 1	2.5 $\pm$ 0.2	—	37	
			3.3 $\pm$ 0.3	—	25	
			5.0 $\pm$ 0.5	—	19	
Output disable time	$t_{PLZ}, t_{PHZ}$	$C_L = 15$ pF $R_L = 1$ k $\Omega$ See 12. AC Test Circuit, Figure 1	2.5 $\pm$ 0.2	—	28.5	ns
			3.3 $\pm$ 0.3	—	18	
			5.0 $\pm$ 0.5	—	12	
		$C_L = 50$ pF $R_L = 1$ k $\Omega$ See 12. AC Test Circuit, Figure 1	2.5 $\pm$ 0.2	—	37	
			3.3 $\pm$ 0.3	—	25	
			5.0 $\pm$ 0.5	—	19	



**11.7. Analog Switch Characteristics (T<sub>a</sub> = 25 °C) (Note)**

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Typ.	Unit	
Sine Wave Distortion	THD	R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 50 pF, f <sub>IN</sub> = 1 kHz	V <sub>IN</sub> = 2.0 V <sub>p-p</sub>	3.0	0.1	%
			V <sub>IN</sub> = 4.0 V <sub>p-p</sub>	4.5	0.03	
Maximum frequency response (switch ON)	f <sub>MAX(I/O)</sub>	V <sub>IN</sub> is centered at (V <sub>CC</sub> /2). Adjust input for 0dBm. Increase f <sub>IN</sub> frequency until dB meter reads -3dB. R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 10 pF, sine wave See 12. AC Test Circuit, Figure 3	3.0	250	MHz	
			4.5	290		
Feed through attenuation (switch OFF)	FTH	V <sub>IN</sub> is centered at (V <sub>CC</sub> /2). Adjust input for 0dBm. R <sub>L</sub> = 600 Ω, C <sub>L</sub> = 50 pF, f <sub>IN</sub> = 1 MHz, sine wave See 12. AC Test Circuit, Figure 4	3.0	-45	dB	
			4.5	-45		
			3.0	-65		
			4.5	-65		
Crosstalk (control input to signal output)	X <sub>talk</sub>	R <sub>L</sub> = 600 Ω, C <sub>L</sub> = 50 pF, f <sub>IN</sub> = 1 MHz, square wave (tr = tf = 6 ns) See 12. AC Test Circuit, Figure 5	3.0	60	mV	
			4.5	100		
Crosstalk (between any switches)	X <sub>talk</sub>	V <sub>IN</sub> is centered at (V <sub>CC</sub> /2). Adjust input for 0dBm. R <sub>L</sub> = 600 Ω, C <sub>L</sub> = 50 pF, f <sub>IN</sub> = 1 MHz, sine wave See 12. AC Test Circuit, Figure 6	3.0	-45	dB	
			4.5	-45		

Note: These characteristics are determined by design of devices.

12. AC Test Circuit

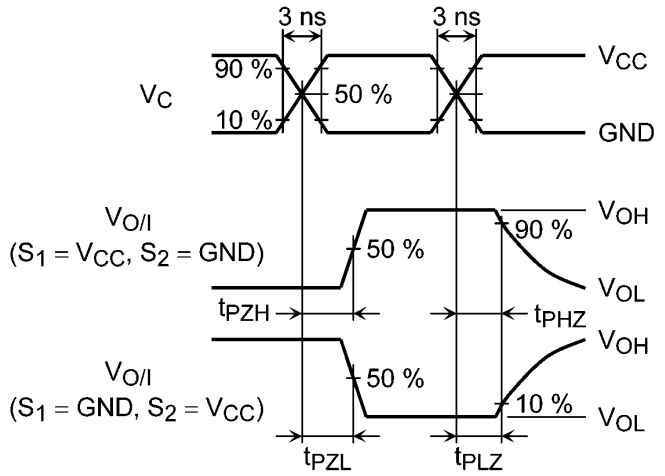
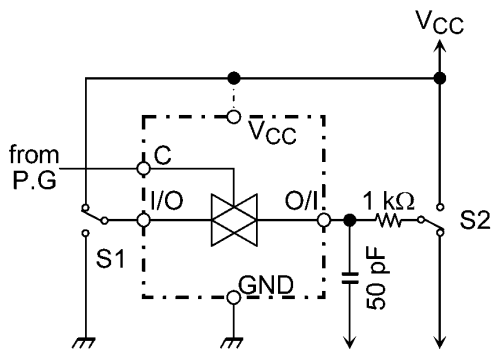


Figure 1  $t_{PZH}$ ,  $t_{PHZ}$ ,  $t_{PZL}$ ,  $t_{PLZ}$

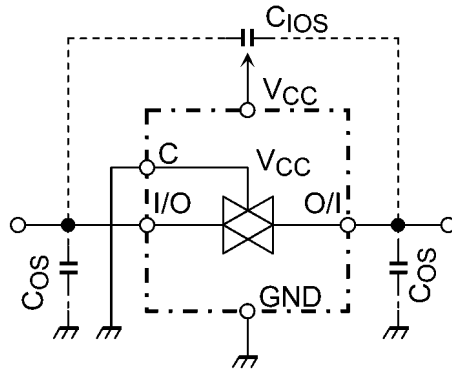


Figure 2  $C_{ios}$ ,  $C_{os}$

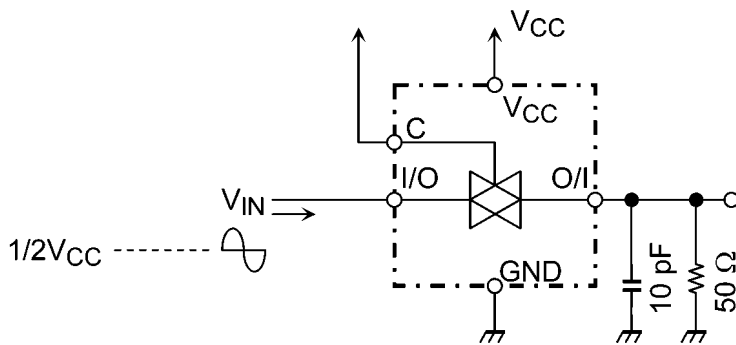
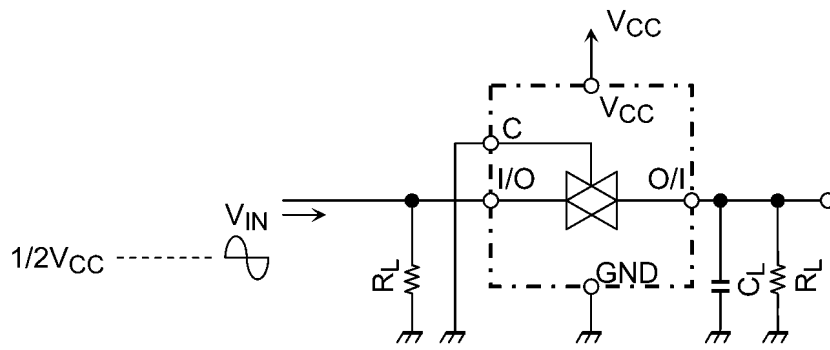
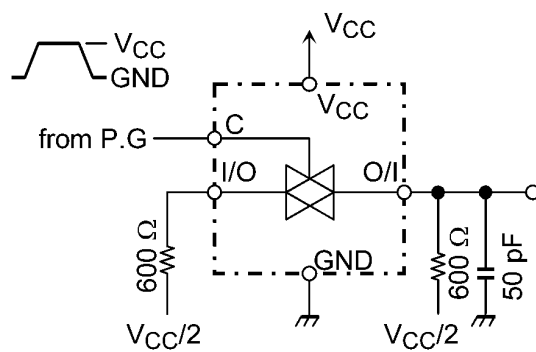


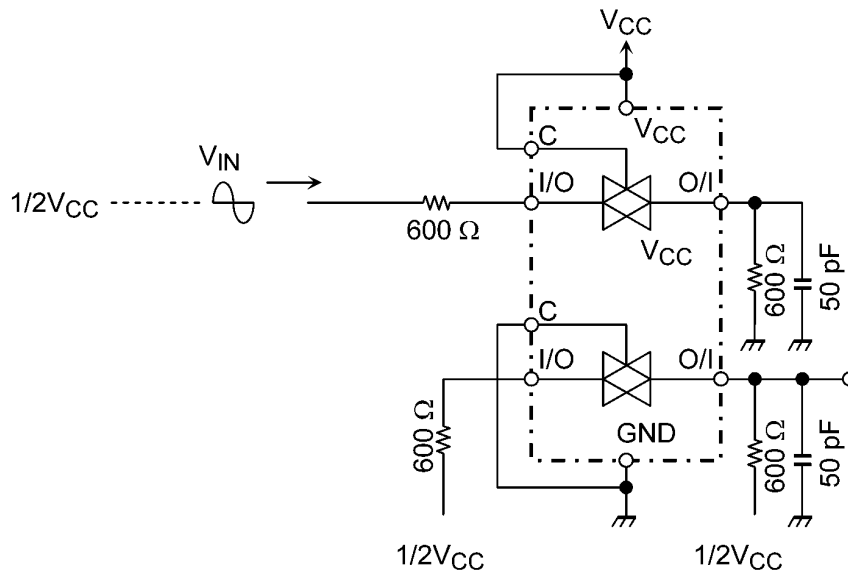
Figure 3 Frequency Response (switch on)



**Figure 4 Feedthrough**



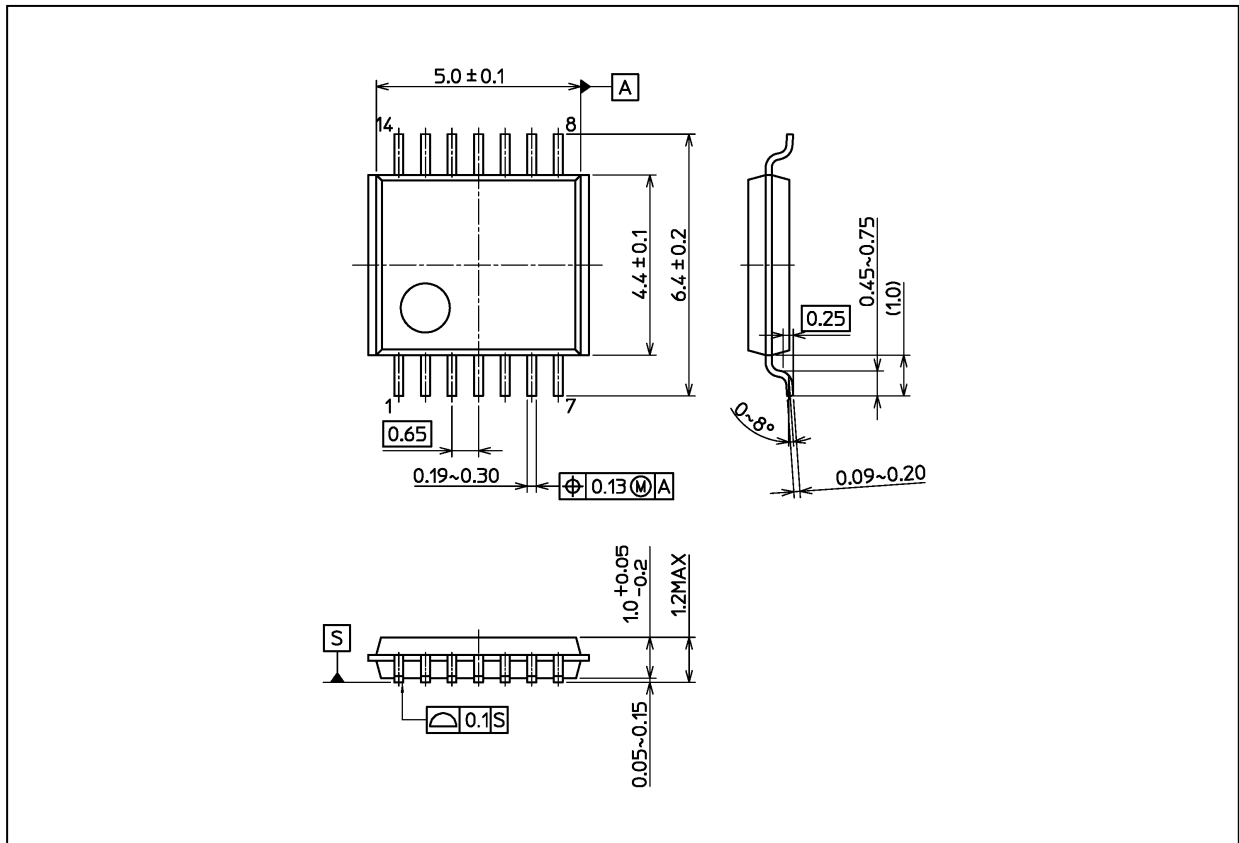
**Figure 5 Cross Talk (control input to output signal)**



**Figure 6 Cross Talk (between any two switches)**

Package Dimensions

Unit: mm



Weight: 0.054 g (typ.)

Package Name(s)
Nickname: TSSOP14B

## RESTRICTIONS ON PRODUCT USE

- Toshiba Corporation, and its subsidiaries and affiliates (collectively "TOSHIBA"), reserve the right to make changes to the information in this document, and related hardware, software and systems (collectively "Product") without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. **TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.**
- **PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").** Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, medical equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to control combustions or explosions, safety devices, elevators and escalators, devices related to electric power, and equipment used in finance-related fields. **IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT.** For details, please contact your TOSHIBA sales representative.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- **ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.**
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. **TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.**

# Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Toshiba:](#)

[74VHC4066AFT](#)



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.